





20V NPN SILICON LOW SATURATION TRANSISTOR IN SOT-23

Features

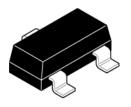
- $V_{CEO} = 20V$
- $I_{C} = 2.5A$
- 625mW Power dissipation
- Low Equivalent On Resistance
- Low Saturation Voltage
- hFE characterised up to 6.0A
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free, "Green" Devices (Note 2)

Mechanical Data

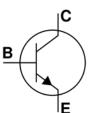
- Case: SOT-23
- Case material: "Green" molding Compound. (Note 2)
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.008 grams (Approximate)

Applications

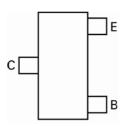
- DC-DC Modules
- Gate driver
- LED driver







Device Symbol



Top View Pin Configuration

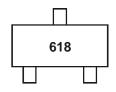
Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT618TA	618	7	8mm embossed	3000 units

Notes:

- No purposefully added lead.
 Devices with the PID number starting from PID0155145 are 'Green' products. Halogen and Antimony Free. Diodes Inc.'s "Green" Policy can be found on our website at https://www.diodes.com/
- 3. For packaging details, go to our website at http://www.diodes.com.

Marking Information



618 = Product Type Marking Code



Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	20	V
Collector-Emitter Voltage	V _{CEO}	20	V
Emitter-Base Voltage	V _{EBO}	5	V
Continuous Collector Current	Ic	2.5	Α
Peak Pulse Current (Note 4)	I _{CM}	6	Α
Base Current	I _B	500	mA

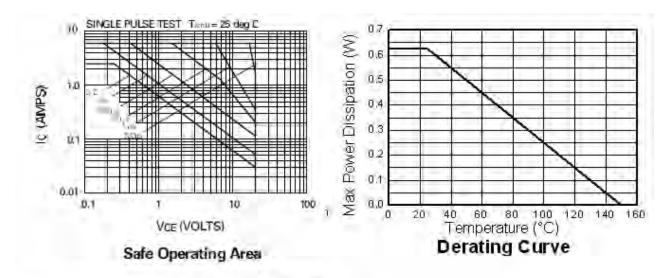
Thermal Characteristics

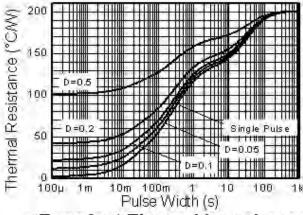
Characteristic	Symbol	Value	Unit
Power Dissipation at T _A = 25°C (Note 5)	P_{D}	625	mW
Thermal Resistance, Junction to Ambient Air (Note 4) @ T _A = 25°C	$R_{ hetaJA}$	200	°C/W
Operating and Storage Temperature Range	$T_{J_1}T_{STG}$	-55 to +150	°C

Notes:

- 4. Measured under pulsed conditions. Pulse width = 300µs. Duty cycle ≤ 2%.
- 5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions.

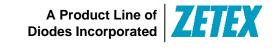
Thermal Characteristics and Derating information





Transient Thermal Impedance





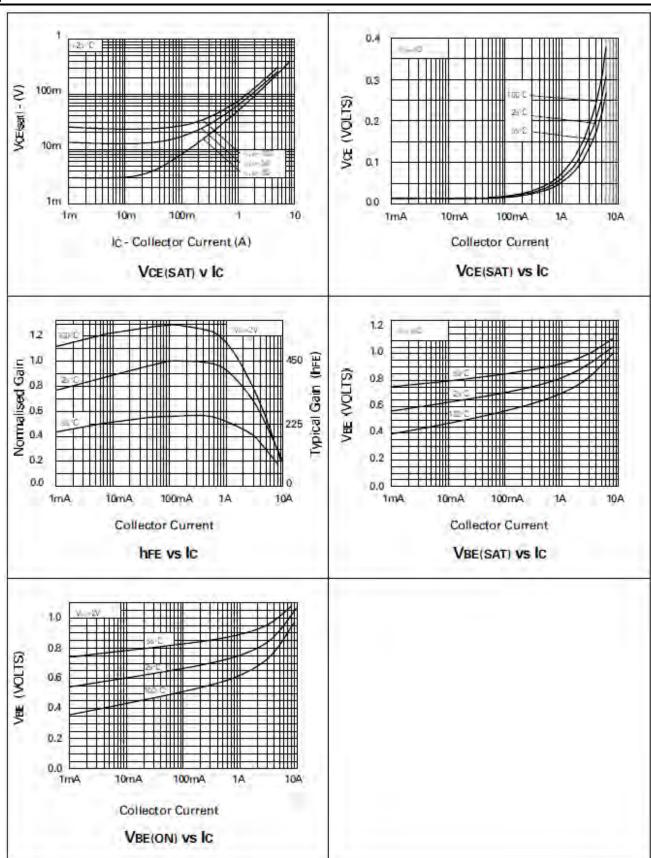
Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	20	100	-	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 6)	$V_{(BR)CEO}$	20	27	-	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	5	8.3	-	V	$I_E = 100\mu A$
Collector Cut-off Current	I _{CBO}	-	-	100	nA	V _{CB} =16V
Emitter Cut-off Current	I _{EBO}	-	-	100	nA	$V_{EB} = 4V$
Collector Emitter Cut-off Current	I _{CES}	-	-	100	nA	V _{CES} =16V
Static Forward Current Transfer Ratio (Note 6)	h _{FE}	200 300 200 100	400 450 360 180	- - -	-	$\begin{split} I_{C} &= 10 \text{mA}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 200 \text{mA}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 2 \text{A}, \ V_{CE} = 2 \text{V} \\ I_{C} &= 6 \text{A}, \ V_{CE} = 2 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}		8 70 130	15 150 200	mV	I_C =0.1A, I_B = 10mA I_C =1A, I_B = 10mA I_C =2.5A, I_B = 50mA
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}	-	0.89	1.0	V	$I_C = 2.5A$, $I_B = 50mA$
Base-Emitter Saturation Voltage (Note 6)	V _{BE(on)}	-	0.79	1.0	V	I _C =2.5A, V _{CE} = 2V
Transition Frequency	f _T	100	140	-	MHz	$I_C = 50 \text{mA}, V_{CE} = 10 \text{V},$ f=100MHz
Collector Output Capacitance	C_obo	-	23	30	pF	V _{CB} = 10V, f=1MHz
Turn-On Time	t _(on)	-	170	-	ns	$V_{CC} = 10V, I_C = 1A,$
Turn-Off Time	t _(off)	-	400	-	ns	$I_{B1} = -I_{B2} = 10 \text{mA}$

Notes: 6. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$

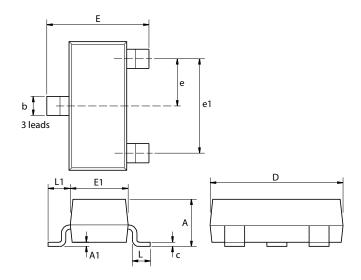


Typical Characteristics





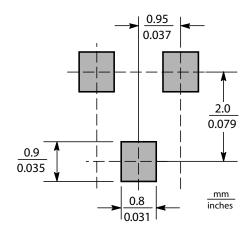
Package Outline Dimensions



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
Α	-	1.12	-	0.044	e1	1.90 NOM		0.075 NOM	
A1	0.01	0.10	0.0004	0.004	Е	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
С	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
е	0.95 NOM		0.037	NOM	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

Suggested Pad Layout







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